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Vishay Siliconix

# Automotive N-Channel 40 V (D-S) 175 °C MOSFET

### **DESCRIPTION**

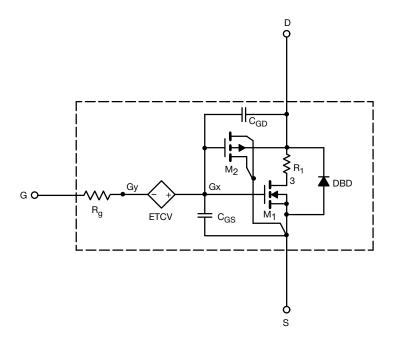
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The subcircuit model is extracted and optimized over -55 °C to +125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{\rm gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### **CHARACTERISTICS**

- N-channel vertical DMOS
- · Macro model (subcircuit model)
- Level 3 MOS
- · Apply for both linear and switching application
- Accurate over -55 °C to +125 °C temperature range
- Model the gate charge

### SUBCIRCUIT MODEL SCHEMATIC



## Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



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SPECIFICATIONS (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate-Source Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \mu A$	3	3	V
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DSö(on)</sub>	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 20 A	0.0008	0.0008	Ω
Forward Transconductance a	9 <sub>fs</sub>	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 15 A	308	122	S
Diode Forward Voltage <sup>a</sup>	V <sub>SD</sub>	I <sub>F</sub> = 50 A	0.8	0.8	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	10 900	11 367	pF
Output Capacitance	C <sub>oss</sub>		5990	6000	
Reverse Transfer Capacitance	C <sub>rss</sub>		470	615	
Total Gate Charge <sup>c</sup>	Qg		135	125	
Gate-Source Charge <sup>c</sup>	Q <sub>gs</sub>	$V_{DS} = 20 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 10 \text{ A}$	40	35	nC
Gate-Drain Charge <sup>c</sup>	Q <sub>gd</sub>		16	13	İ

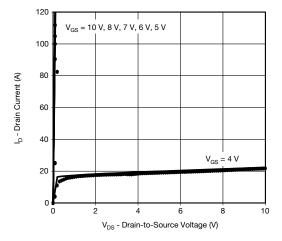
#### Notes

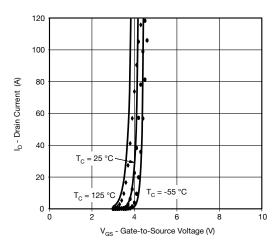
- a. Pulse test; pulse width  $\leq 300~\mu s,$  duty cycle  $\leq 2~\%$
- b. Guaranteed by design, not subject to production testing

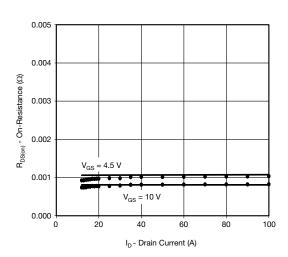
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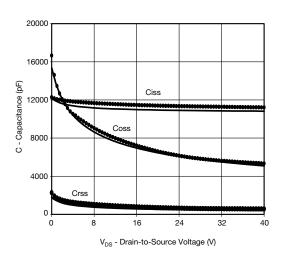
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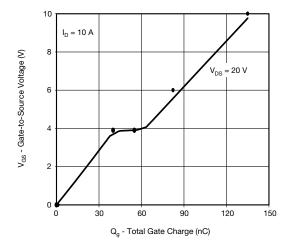
## **COMPARISON OF MODEL WITH MEASURED DATA** ( $T_J = 25$ °C, unless otherwise noted)

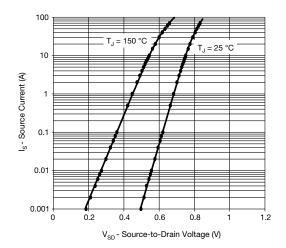












## Note

· Dots and squares represent measured data.

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